

National Semiconductor

LP38500/2-ADJ, LP38500A/2A-ADJ 1.5A FlexCap Low Dropout Linear Regulator for 2.7V to 5.5V Inputs

General Description

National's FlexCap LDO's feature unique compensation that allows the use of any type of output capacitor with no limits on minimum or maximum ESR. The LP38500/2 series of low-dropout linear regulators operates from a +2.7V to +5.5V input supply. These ultra low dropout linear regulators respond very quickly to step changes in load, which makes them suitable for low voltage microprocessor applications. Developed on a CMOS process, (utilizing a PMOS pass transistor), the LP38500/2 has low quiescent current that changes little with load current.

Ground Pin Current: Typically 2 mA at 1.5A load current.

Disable Mode: Typically 25 nA quiescent current when the Enable pin is pulled low.

Simplified Compensation: Stable with any type of output capacitor, regardless of ESR.

Precision Output: "A" grade versions available with 1.5% V_{ADJ} tolerance (25°C) and 3% over line, load and temperature.

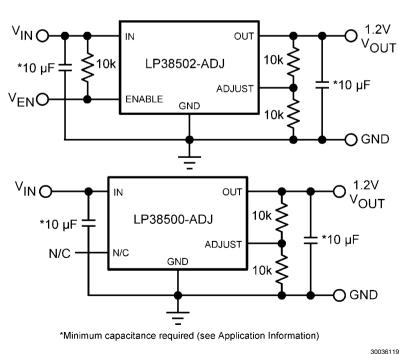
Features

- FlexCap: Stable with ceramic, tantalum, or aluminum capacitors
- Stable with 10 µF input/output capacitor
- Adjustable output voltage from 0.6V to 5V
- Low ground pin current
- 25 nA quiescent current in shutdown mode
- Guaranteed output current of 1.5A
- Available in TO-263, TO-263 THIN, and LLP-8 packages
- Guaranteed V_{ADJ} accuracy of ±1.5% @ 25°C (A Grade)
- Guaranteed accuracy of ±3.5% @ 25°C (STD)
- Over-Temperature and Over-Current protection
- -40°C to +125°C operating T_J range
- Enable pin (LP38502)

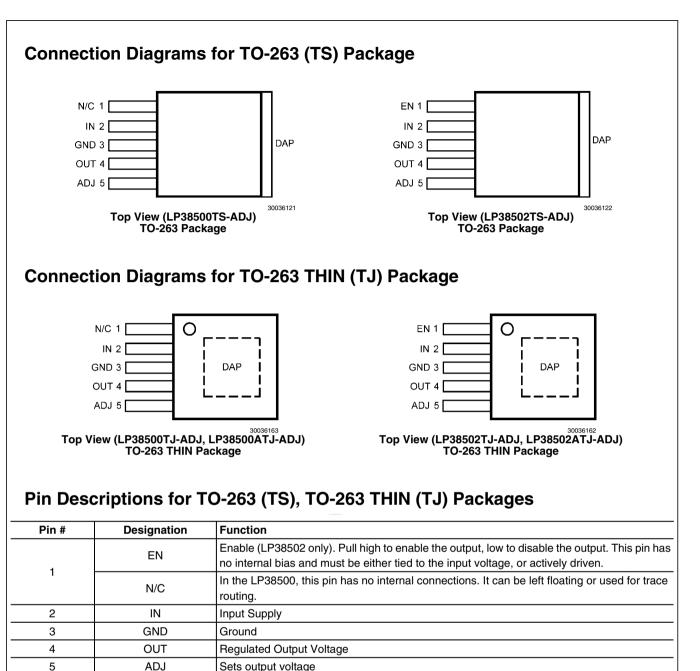
Applications

- ASIC Power Supplies In: Printers, Graphics Cards, DVD Players Set Top Boxes, Copiers, Routers
- DSP and FPGA Power Supplies
- SMPS Regulator
- Conversion from 3.3V or 5V Rail

Typical Application Circuit



May 19, 2008



DAP

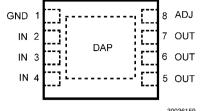
DAP

connection.

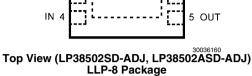
The DAP is used to remove heat from the device by conducting it to the copper clad area on the PCB which acts as the heatsink. The DAP is electrically connected to the backside of the

die. The DAP must be connected to ground potential, but can not be used as the only ground

Connection Diagrams for LLP-8 (SD) Package







DAP

ADJ

7 OUT

6 OUT

8

GND

EN 2

IN 3

Pin Descriptions for LLP-8 (SD) Package

Pin #	Designation	Function
1	GND	Ground
2	IN	Input Supply (LP38500 only). Input Supply pins share current and must be connected together on the PC Board.
2	EN	Enable (LP38502 only). Pull high to enable the output, low to disable the output. This pin has no internal bias and must be either tied to the input voltage, or actively driven.
3, 4	IN	Input Supply. Input Supply pins share current and must be connected together on the PC Board.
5, 6, 7	OUT	Regulated Output Voltage. Output pins share current and must be connected together on the PC Board.
8	ADJ	Sets output voltage
DAP	DAP	The DAP is used to remove heat from the device by conducting it to a copper clad area on the PCB which acts as a heatsink. The DAP is electrically connected to the backside of the die. The DAP must be connected to ground potential, but can not be used as the only ground connection.

Ordering Information

TABLE 1. Package Marking and Ordering Information

Output Voltage	Order Number	Package Type	Package Marking	Supplied As:
	LP38500SDX-ADJ		LP38500SD-ADJ	Tape and Reel of 4500 Unit
	LP38500SD-ADJ	Γ	LP38500SD-ADJ	Tape and Reel of 1000 Unit
	LP38502SDX-ADJ	Γ	LP38502SD-ADJ	Tape and Reel of 4500 Unit
	LP38502SD-ADJ		LP38502SD-ADJ	Tape and Reel of 1000 Uni
ADJ -	LP38500ASDX-ADJ	- LLP-8 -	LP38500ASD-ADJ	Tape and Reel of 4500 Unit
	LP38500ASD-ADJ	η Γ	LP38500ASD-ADJ	Tape and Reel of 1000 Uni
	LP38502ASDX-ADJ	Γ	LP38502ASD-ADJ	Tape and Reel of 4500 Uni
	LP38502ASD-ADJ		LP38502ASD-ADJ	Tape and Reel of 1000 Uni
	LP38500TSX-ADJ		LP38500TS-ADJ	Tape and Reel of 500 Unit
ADJ	LP38500TS-ADJ	ТО-263	LP38500TS-ADJ	Rail of 45 Units
ADJ	LP38502TSX-ADJ	10-203	LP38502TS-ADJ	Tape and Reel of 500 Unit
	LP38502TS-ADJ]	LP38502TS-ADJ	Rail of 45 Units
	LP38500TJ-ADJ		LP38500TJ-ADJ	Tape and Reel of 1000 Unit
ADJ	LP38502TJ-ADJ		LP38502TJ-ADJ	Tape and Reel of 1000 Unit
ADJ	LP38500ATJ-ADJ		LP38500ATJ-ADJ	Tape and Reel of 1000 Unit
Γ	LP38502ATJ-ADJ	Γ	LP38502ATJ-ADJ	Tape and Reel of 1000 Unit

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range	–65°C to +150°C
Lead Temperature	
(Soldering, 5 sec.)	260°C
ESD Rating (Note 2)	±2 kV
Power Dissipation(Note 3)	Internally Limited
Input Pin Voltage (Survival)	-0.3V to +6.0V
Enable Pin Voltage (Survival)	-0.3V to +6.0V
Output Pin Voltage (Survival)	-0.3V to +6.0V
I _{OUT} (Survival)	Internally Limited

Operating Ratings (Note 1)

Input Supply Voltage	2.7V to 5.5V
Enable Input Voltage	0.0V to 5.5V
Output Current (DC)	0 to 1.5A
Junction Temperature(Note 3)	-40°C to +125°C
V _{OUT}	0.6V to 5V

Electrical Characteristics LP38500/2-ADJ

Unless otherwise specified: $V_{IN} = 3.3V$, $I_{OUT} = 10$ mA, $C_{IN} = 10 \mu$ F, $C_{OUT} = 10 \mu$ F, $V_{EN} = V_{IN}$, $V_{OUT} = 1.8V$. Limits in standard type are for $T_J = 25^{\circ}$ C only; limits in **boldface type** apply over the junction temperature (T_J) range of -40°C to +125°C. Minimum and Maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^{\circ}$ C, and are provided for reference purposes only.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
V _{ADJ}	Adjust Pin Voltage (Note 6)	$2.7V \le V_{IN} \le 5.5V$ 10 mA $\le I_{OUT} \le 1.5A$	0.584 0.575	0.605	0.626 0.635	V	
V _{ADJ}	Adjust Pin Voltage (Note 6) "A" GRADE	$2.7V \le V_{ N} \le 5.5V$ 10 mA $\le I_{OUT} \le 1.5A$	0.596 0.587	0.605	0.614 0.623	v	
I _{ADJ}	Adjust Pin Bias Current	$2.7V \le V_{IN} \le 5.5V$		50	750	nA	
V _{DO}	Dropout Voltage (Note 7)	I _{OUT} = 1.5A		220	275 375	mV	
ΔV _{OUT} /ΔV _{IN}	Output Voltage Line Regulation (Notes 4, 6)	2.7V ≤ V _{IN} ≤ 5.5V	_	0.04 0.05	_	%/V	
ΔV _{OUT} /ΔI _{OUT}	Output Voltage Load Regulation (Notes 5, 6)	10 mA ≤ I _{OUT} ≤ 1.5A	_	0.18 0.33	_	%/A	
I _{GND}	Ground Pin Current In Normal Operation Mode	10 mA ≤ I _{OUT} ≤ 1.5A		2	3.5 4.5	mA	
I _{DISABLED}	Ground Pin Current	$V_{EN} < V_{IL(EN)}$	_	0.025	0.125 15	μA	
I _{OUT(PK)}	Peak Output Current	V _{OUT} ≥ V _{OUT(NOM)} - 5%		3.6		A	
I _{SC}	Short Circuit Current	V _{OUT} = 0V	2	3.7		A	
nable Input ((LP38502 Only)			•		•	
V _{IH(EN)}	Enable Logic High	V _{OUT} = ON	1.4	_	_	v	
V _{IL(EN)}	Enable Logic Low	V _{OUT} = OFF	_	_	0.65		
t _{d(off)}	Turn-off delay	Time from $V_{EN} < V_{IL(EN)}$ to $V_{OUT} =$ OFF $I_{LOAD} = 1.5A$	_	25	_		
t _{d(on)}	Turn-on delay	Time from $V_{EN} > V_{IH(EN)}$ to $V_{OUT} = ON$ $I_{LOAD} = 1.5A$		25	_	μs	
I _{IH(EN)}	Enable Pin High Current	$V_{\rm EN} = V_{\rm IN}$	_	1	—	-	
I _{IL(EN)}	Enable Pin Low Current	V _{EN} = 0V		0.1		nA	

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
C Paramete	ers		•				
	Ripple Rejection	V _{IN} = 3.0V, I _{OUT} = 1.5A f = 120Hz	_	58	_	dB	
PSRR		V _{IN} = 3.0V, I _{OUT} = 1.5A f = 1 kHz	_	56	_		
ρ _{n(l/f)}	Output Noise Density	f = 120Hz, C _{OUT} = 10 μF CER	-	1.0	—	µV/√Hz	
e _n	Output Noise Voltage	BW = 100Hz – 100kHz C _{OUT} = 10 μF CER	_	100	_	μV (rms)	
ermal Cha	racteristics						
T_{SD}	Thermal Shutdown	T _J rising	_	170	_	- °C	
ΔT_{SD}	Thermal Shutdown Hysteresis	T_J falling from T_{SD}	_	10	—		
٥	Thermal Resistance Junction to Ambient	TO-263, TO-263 THIN(Note 8) 1 sq. in. copper	_	37	_		
θ_{J-A}	Thermal Resistance Junction to Ambient	LLP-8 (Note 9)	_	80	_	- °C/W	
0	Thermal Resistance	TO-263, TO-263 THIN	_	5	_	°C/W	
θ^{1-C}	Junction to Case	LLP-8	_	16	_	7 0/10	

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but does not guarantee specific performance limits. For guaranteed specifications and conditions, see the Electrical Characteristics. Note 2: The human body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin.

Note 3: Operating junction temperature must be evaluated, and derated as needed, based on ambient temperature (T_A), power dissipation (P_D), maximum allowable operating junction temperature ($T_{J(MAX)}$), and package thermal resistance (θ_{JA}). See Application Information.

Note 4: Output voltage line regulation is defined as the change in output voltage from the nominal value due to change in the voltage at the input.

Note 5: Output voltage load regulation is defined as the change in output voltage from the nominal value due to change in the load current.

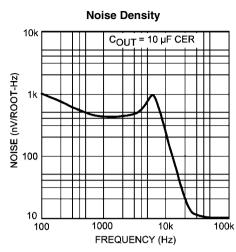
Note 6: The line and load regulation specification contains only the typical number. However, the limits for line and load regulation are included in the adjust voltage tolerance specification.

Note 7: Dropout voltage is defined as the minimum input to output differential voltage at which the output drops 2% below the nominal value. For any output voltage less than 2.5V, the minimum V_{IN} operating voltage is the limiting factor.

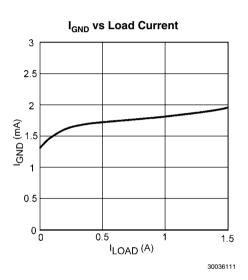
Note 8: The value of θ_{JA} for the TO-263 (TS) package and TO-263 THIN (TJ) package can range from approximately 30 to 60°C/W depending on the amount of PCB copper dedicated to heat transfer (See Application Information).

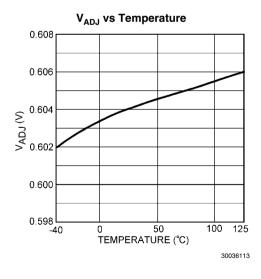
Note 9: θ_{JA} for the LLP-8 package was measured using the LP38502SD-ADJ evaluation board (See Application Information).

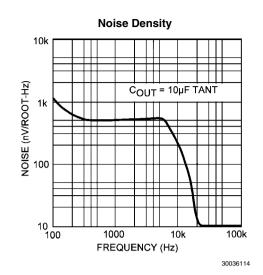
Typical Performance Characteristics Unless otherwise specified: $T_J = 25^{\circ}C$, $V_{IN} = 2.7V$, $V_{EN} = V_{IN}$, $C_{IN} = 10 \ \mu$ F, $C_{OUT} = 10 \ \mu$ F, $I_{OUT} = 10 \ m$ A, $V_{OUT} = 1.8V$



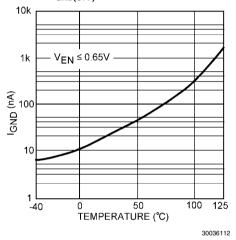
30036110



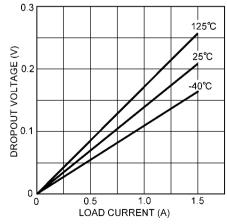




I_{GND(OFF)} vs Temperature

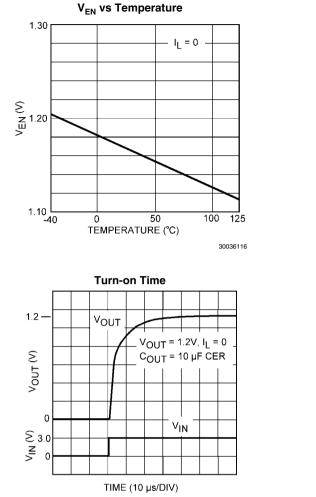


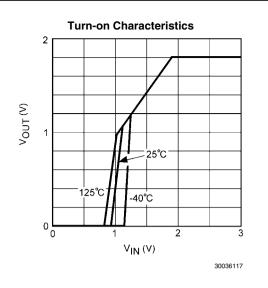
Dropout Voltage vs Load Current

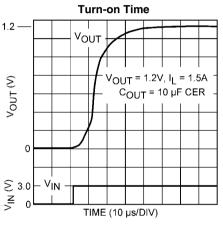


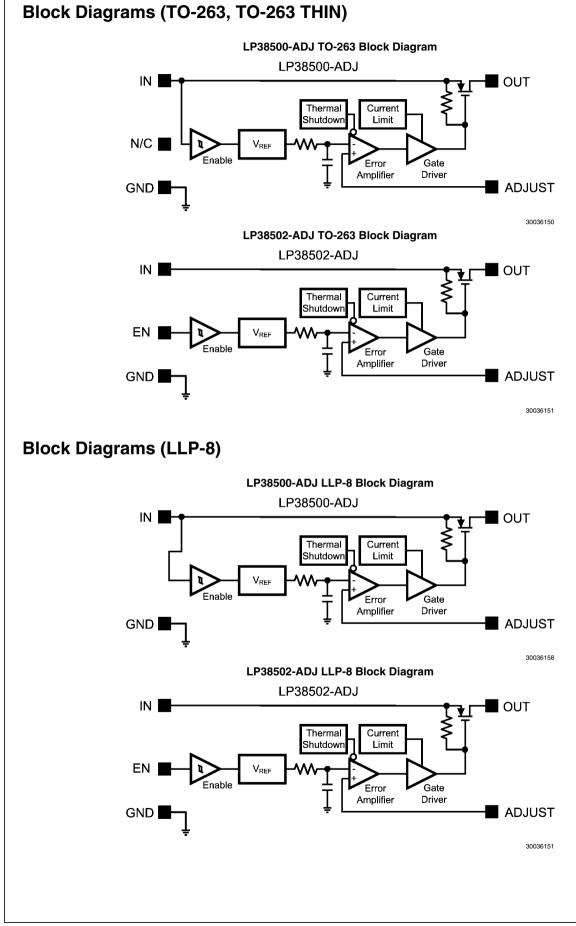
30036115











Application Information EXTERNAL CAPACITORS

The LP3850X requires that at least 10 μ F (±20%) capacitors be used at the input and output pins located within one cm of the IC. Larger capacitors may be used without limit on size for both C_{IN} and C_{OUT}. Capacitor tolerances such as temperature variation and voltage loading effects must be considered when selecting capacitors to ensure that they will provide the minimum required amount of capacitance under all operating conditions for the application.

In general, ceramic capacitors are best for noise bypassing and transient response because of their ultra low ESR. It must be noted that if ceramics are used, only the types with X5R or X7R dielectric ratings should be used (never Z5U or Y5F). Capacitors which have the Z5U or Y5F characteristics will see a drop in capacitance of as much as 50% if their temperature increases from 25°C to 85°C. In addition, the capacitance drops significantly with applied voltage: a typical Z5U or Y5F capacitor can lose as much as 60% of it's rated capacitance if only half of the rated voltage is applied to it. For these reasons, only X5R and X7R ceramics should be used.

INPUT CAPACITOR

All linear regulators can be affected by the source impedance of the voltage which is connected to the input. If the source impedance is too high, the reactive component of the source may affect the control loop's phase margin. **To ensure proper loop operation, the ESR of the capacitor used for C**_{IN} **must not exceed 0.5 Ohms**. Any good quality ceramic capacitor will meet this requirement, as well as many good quality tantalums. Aluminum electrolytic capacitors may also work, but can possibly have an ESR which increases significantly at cold temperatures. If the ESR of the input capacitor may exceed 0.5 Ohms, it is recommended that a 2.2 µF ceramic capacitor be used in parallel, as this will assure stable loop operation.

OUTPUT CAPACITOR

Any type of capacitor may be used for C_{OUT} , with no limitations on minimum or maximum ESR, as long as the minimum amount of capacitance is present. The amount of capacitance can be increased without limit. Increasing the size of C_{OUT} typically will give improved load transient response.

SETTING THE OUTPUT VOLTAGE

The output voltage of the LP38500/2-ADJ can be set to any value between 0.6V and 5V using two external resistors shown as R1 and R2 in *Figure 1*.

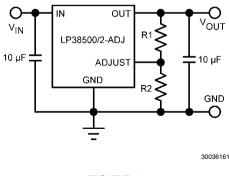


FIGURE 1.

The value of R2 should always be less than or equal to 10 $k\Omega$ for good loop compensation. R1 can be selected for a given V_{OUT} using the following formula:

$$V_{OUT} = V_{ADJ} (1 + R1/R2) + I_{ADJ} (R1)$$

Where V_{ADJ} is the adjust pin voltage and I_{ADJ} is the bias current flowing into the adjust pin.

STABILITY AND PHASE MARGIN

Any regulator which operates using a feedback loop must be compensated in such a way as to ensure adequate phase margin, which is defined as the difference between the phase shift and -180 degrees at the frequency where the loop gain crosses unity (0 dB). For most LDO regulators, the ESR of the output capacitor is required to create a zero to add enough phase lead to ensure stable operation. The LP38500/2-ADJ has a unique internal compensation circuit which maintains phase margin regardless of the ESR of the output capacitor, so any type of capacitor may be used.

Figure 2 shows the gain/phase plot of the LP38500/2-ADJ with an output of 1.2V, 10 μ F ceramic output capacitor, delivering 1.5A of load current. It can be seen that the unity-gain crossover occurs at 150 kHz, and the phase margin is about 40° (which is very stable).

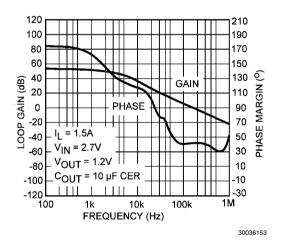


FIGURE 2. Gain-Bandwidth Plot for 1.5A Load

Figure 3 shows the gain and phase with no external load. In this case, the only load is provided by the gain setting resistors (about 12 k Ω total in this test). It is immediately obvious that the unity-gain frequency is significantly lower (dropping to about 500 Hz), at which point the phase margin is 125°.

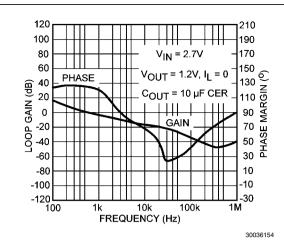


FIGURE 3. Gain-Bandwidth Plot for No Load

The reduction in unity-gain bandwidth as load current is reduced is normal for any LDO regulator using a P-FET or PNP pass transistor, because they have a pole in the loop gain function given by:

$$F_{P} = \frac{1}{2 \times \pi \times R_{I} \times C_{OUT}}$$

This illustrates how the pole goes to the highest frequency when R_L is minimum value (maximum load current). In general, LDO's have maximum bandwidth (and lowest phase margin) at full load current. In the case of the LP38500/2-ADJ, it can be seen that it has good phase margin even when using ceramic capacitors with ESR values of only a few milli Ohms.

LOAD TRANSIENT RESPONSE

Load transient response is defined as the change in regulated output voltage which occurs as a result of a change in load current. Many applications have loads which vary, and the control loop of the voltage regulator must adjust the current in the pass FET transistor in response to load current changes. For this reason, regulators with wider bandwidths often have better transient response.

The LP38500/2-ADJ employs an internal feedforward design which makes the load transient response much faster than would be predicted simply by loop speed: this feedforward means any voltage changes appearing on the output are coupled through to the high-speed driver used to control the gate of the pass FET along a signal path using very fast FET devices. Because of this, the pass transistor's current can change very quickly.

Figure 3 shows the output voltage load transient which occurs on a 1.8V output when the load changes from 0.1A to 1.5A at an average slew rate of $0.5A/\mu s$. As shown, the peak output voltage change from nominal is about 40 mV, which is about 2.2%.

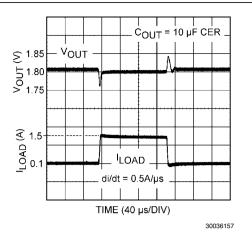


FIGURE 4. Load Transient Response

In cases where extremely fast load changes occur, the output capacitance may have to be increased. When selecting capacitors, it must be understood that the better performing ones usually cost the most. For fast changing loads, the internal parasitics of ESR (equivalent series resistance) and ESL (equivalent series inductance) degrade the capacitor's ability to source current quickly to the load. The best capacitor types for transient performance are (in order):

- Multilayer Ceramic: with the lowest values of ESR and ESL, they can have ESR values in the range of a few milli Ohms. Disadvantage: capacitance values above about 22 µF significantly increase in cost.
- 2. Low-ESR Aluminum Electrolytics: these are aluminum types (like OSCON) with a special electrolyte which provides extremely low ESR values, and are the closest to ceramic performance while still providing large amounts of capacitance. These are cheaper (by capacitance) than ceramic.
- Solid tantalum: can provide several hundred µF of capacitance, transient performance is slightly worse than OSCON type capacitors, cheaper than ceramic in large values.
- 4. General purpose aluminum electrolytics: cheap and provide a lot of capacitance, but give the worst performance.

In general, managing load transients is done by paralleling ceramic capacitance with a larger bulk capacitance. In this way, the ceramic can source current during the rapidly changing edge and the bulk capacitor can support the load current after the first initial spike in current.

PRINTED CIRCUIT BOARD LAYOUT

Good layout practices will minimize voltage error and prevent instability which can result from ground loops. The input and output capacitors should be directly connected to the IC pins with short traces that have no other current flowing in them (Kelvin connect).

The best way to do this is to place the capacitors very near the IC and make connections directly to the IC pins via short traces on the top layer of the PCB. The regulator's ground pin should be connected through vias to the internal or backside ground plane so that the regulator has a single point ground.

The external resistors which set the output voltage must also be located very near the IC with all connections directly tied via short traces to the pins of the IC (Kelvin connect). Do not connect the resistive divider to the load point or DC error will be induced.

RFI/EMI SUSCEPTIBILITY

RFI (Radio Frequency Interference) and EMI (Electro-Magnetic Interference) can degrade any integrated circuit's performance because of the small dimensions of the geometries inside the device. In applications where circuit sources are present which generate signals with significant high frequency energy content (> 1 MHz), care must be taken to ensure that this does not affect the IC regulator.

If RFI/EMI noise is present on the input side of the regulator (such as applications where the input source comes from the output of a switching regulator), good ceramic bypass capacitors must be used at the input pin of the IC to reduce the amount of EMI conducted into the IC.

If the LP38500/2-ADJ output is connected to a load which switches at high speed (such as a clock), the high-frequency current pulses required by the load must be supplied by the capacitors on the IC output. Since the bandwidth of the regulator loop is less than 300 kHz, the control circuitry cannot respond to load changes above that frequency. This means the effective output impedance of the IC at frequencies above 300 kHz is determined only by the output capacitor(s). Ceramic capacitors provide the best performance in this type of application.

In applications where the load is switching at high speed, the output of the IC may need RF isolation from the load. In such cases, it is recommended that some inductance be placed between the output capacitor and the load, and good RF by-pass capacitors be placed directly across the load. PCB layout is also critical in high noise environments, since RFI/ EMI is easily radiated directly into PC traces. Noisy circuitry should be isolated from "clean" circuits where possible, and grounded through a separate path. At MHz frequencies, ground planes begin to look inductive and RFI/EMI can cause ground bounce across the ground plane. In multi-layer PC Board applications, care should be taken in layout so that noisy power and ground planes do not radiate directly into adjacent layers which carry analog power and ground.

OUTPUT NOISE

Noise is specified in two ways:

Spot Noise or **Output noise density** is the RMS sum of all noise sources, measured at the regulator output, at a specific frequency (measured with a 1Hz bandwidth). This type of noise is usually plotted on a curve as a function of frequency.

Total output noise voltage or Broadband noise is the RMS sum of spot noise over a specified bandwidth, usually several decades of frequencies. Attention should be paid to the units of measurement.

Spot noise is measured in units $\mu V/\sqrt{Hz}$ or nV/\sqrt{Hz} and total output noise is measured in $\mu V(\text{rms})$. The primary source of noise in low-dropout regulators is the internal reference. In CMOS regulators, noise has a low frequency component and a high frequency component, which depend strongly on the silicon area and quiescent current.

Noise can generally be reduced in two ways: increase the transistor area or increase the reference current. However, enlarging the transisitors will increase die size, and increasing the reference current means higher total supply current (ground pin current).

SHORT-CIRCUIT PROTECTION

The LP38500/2-ADJ contains internal current limiting which will reduce output current to a safe value if the output is overloaded or shorted. Depending upon the value of V_{IN} , thermal limiting may also become active as the average power dissipated causes the die temperature to increase to the limit value

(about 170°C). The hysteresis of the thermal shutdown circuitry can result in a "cyclic" behavior on the output as the die temperature heats and cools.

ENABLE OPERATION (LP38502-ADJ Only)

The Enable pin (EN) must be actively terminated by either a 10 k Ω pull-up resistor to V_{IN}, or a driver which actively pulls high and low (such as a CMOS rail to rail comparator). If active drive is used, the pull-up resistor is not required. This pin must be tied to V_{IN} if not used (it must not be left floating).

DROPOUT VOLTAGE

The dropout voltage of a regulator is defined as the input-tooutput differential required by the regulator to keep the output voltage within 2% of the nominal value. For CMOS LDOs, the dropout voltage is the product of the load current and the $R_{DS(on)}$ of the internal MOSFET pass element.

Since the output voltage is beginning to "drop out" of regulation when it drops by 2%, electrical performance of the device will be reduced compared to the values listed in the Electrical Characteristics table for some parameters (line and load regulation and PSRR would be affected).

REVERSE CURRENT PATH

The internal MOSFET pass element in the LP38500/2-ADJ has an inherent parasitic diode. During normal operation, the input voltage is higher than the output voltage and the parasitic diode is reverse biased. However, if the output is pulled above the input in an application, then current flows from the output to the input as the parasitic diode gets forward biased. The output can be pulled above the input as long as the current in the parasitic diode is limited to 200 mA continuous and 1A peak. The regulator output pin should not be taken below ground potential. If the LP38500/2-ADJ is used in a dual-supply system where the regulator load is returned to a negative supply, the output must be diode-clamped to ground.

POWER DISSIPATION/HEATSINKING

The maximum power dissipation ($P_{D(MAX)}$) of the LP38500/2-ADJ is limited by the maximum junction temperature of 125°C, along with the maximum ambient temperature (T_A (MAX)) of the application, and the thermal resistance (θ_{JA}) of the package. Under all possible conditions, the junction temperature (T_J) must be within the range specified in the Operating Ratings. The total power dissipation of the device is given by:

$$P_{D} = ((V_{IN} - V_{OUT}) \times I_{OUT}) + (V_{IN} \times I_{GND})$$
(1)

where I_{GND} is the operating ground current of the device (specified under Electrical Characteristics).

The maximum allowable junction temperature rise (ΔT_J) depends on the maximum expected ambient temperature $(T_{A(MAX)})$ of the application, and the maximum allowable junction temperature $(T_{J(MAX)})$:

$$\Delta T_{\rm J} = T_{\rm J(MAX)} - T_{\rm A(MAX)} \tag{2}$$

The maximum allowable value for junction to ambient Thermal Resistance, $\theta_{i,lA}$, can be calculated using the formula:

$$\theta_{JA} = \Delta T_J / P_{D(MAX)}$$
(3)

The LP38500/2-ADJ is available in the TO-263 and LLP-8 packages. The thermal resistance depends on the amount of copper area allocated to heat transfer.

HEATSINKING TO-263 and TO-263 THIN PACKAGES

The TO-263 package and TO-263 THIN package use the copper plane on the PCB as a heatsink. The DAP of the package is soldered to the copper plane for heat sinking. *Figure 5* shows a typical curve for the θ_{JA} of the TO-263 package for different copper area sizes (the thermal performance of both TO-263 and TO-263 THIN are the same). The tests were done using a PCB with 1 ounce copper on top side only, with copper patterns which were square in shape.

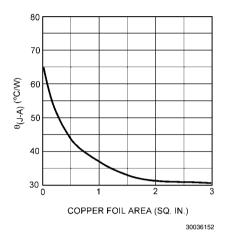


FIGURE 5. θ_{JA} vs Copper Area for TO-263 Package

As shown in the figure, increasing the copper area beyond 1.5 square inch produces very little improvement.

HEATSINKING LLP-8 PACKAGE

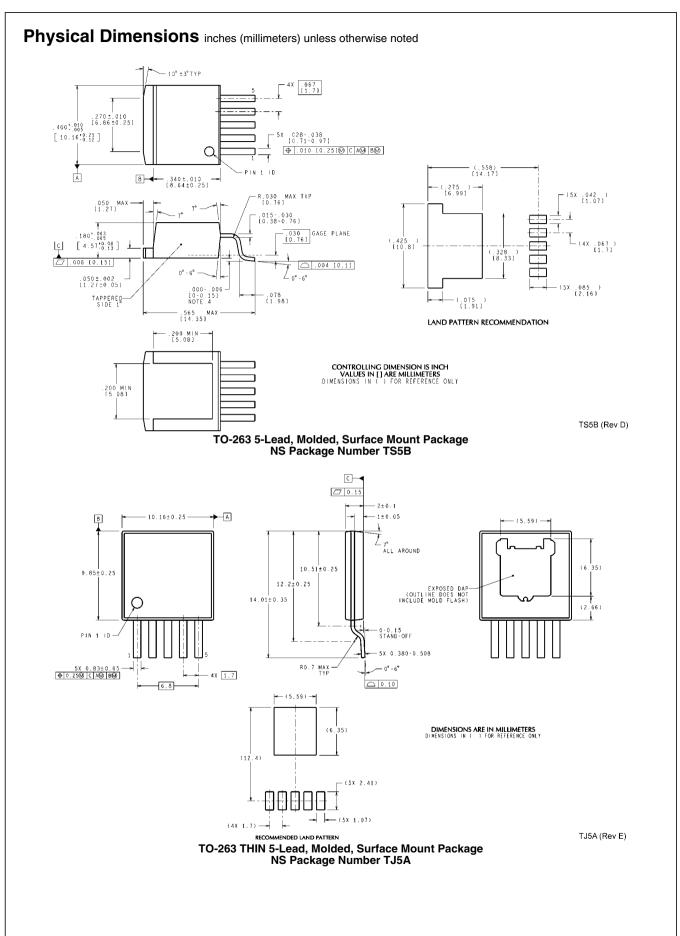
The junction-to-ambient thermal resistance for the LLP-8 package is dependent on how much PCB copper is present to conduct heat away from the device. The LP38502SD-ADJ evaluation board (980600046-100) was tested and gave a result of about 80°C/W with a power dissipation of 1W and no external airflow. This evaluation board is a two layer board using two ounce copper, and the copper area on topside for heatsinking is approximately two square inches. Multiple vias under the DAP also thermally connect to the backside layer which has about three square inches of copper dedicated to heatsinking.

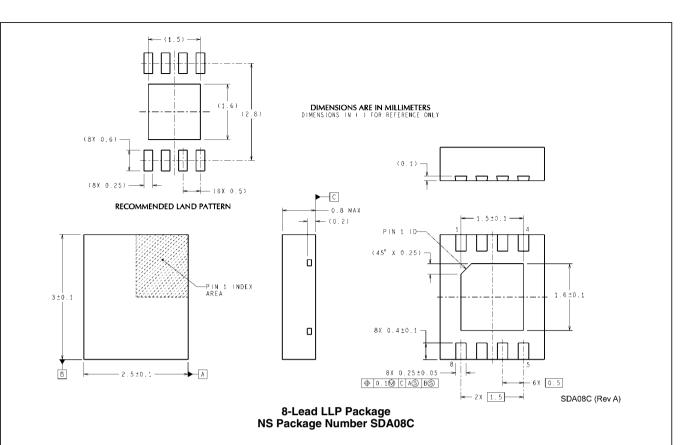
Finite modeling of the LP38502SD-ADJ with a four layer board (JEDEC JESD51-7 and JESD51-5) with one thermal via directly under the DAP to the first copper plane predicts a θ_{JA} of 72°C/W.

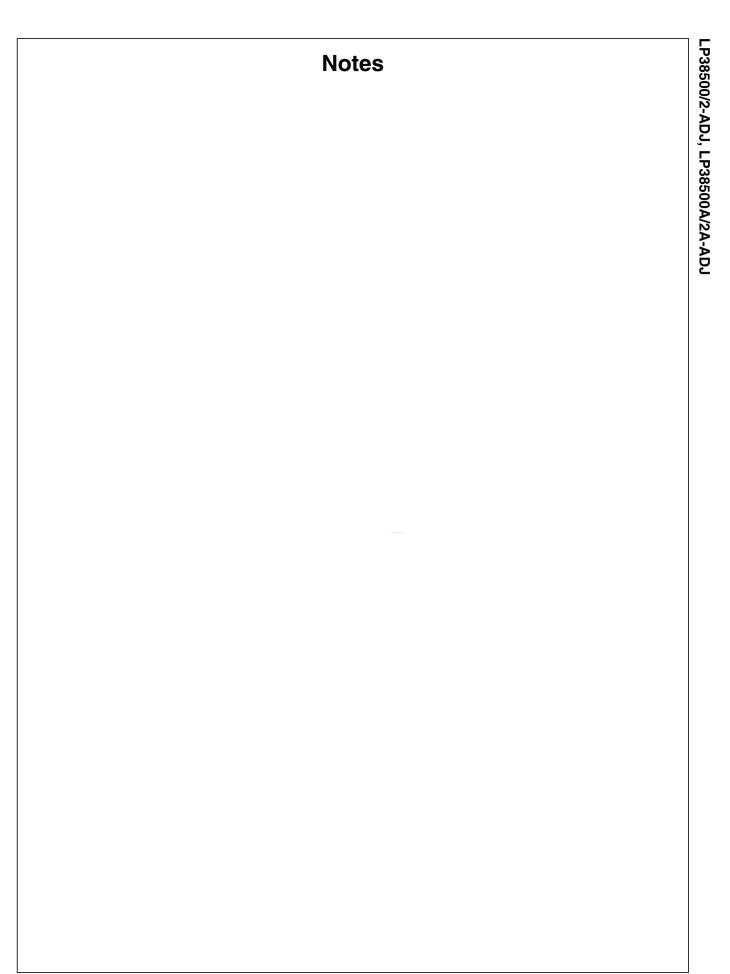
With four thermal vias directly under the DAP to the first copper plane, the modeling predicts a θ_{JA} of 50°C/W.

Adding a dog-bone copper area with four additional thermal vias in the dog-bone area to the first copper plane can improve θ_{JA} to 45C°C/W.

See Application Note *AN-1520 A Guide to Board Layout for Best Thermal Resistance for Exposed Packages* for additional thermal considerations for printed circuit board layouts.







Design Support

www.national.com/refdesigns

www.national.com/feedback

I VDS

Power Management

LED Lighting

Temperature Sensors

Wireless (PLL/VCO)

LDOs

PowerWise

Switching Regulators

Serial Digital Interface (SDI)

Amplifiers	www.national.com/amplifiers	WEBENCH	www.national.com/webench
Audio	www.national.com/audio	Analog University	www.national.com/AU
Clock Conditioners	www.national.com/timing	App Notes	www.national.com/appnotes
Data Converters	www.national.com/adc	Distributors	www.national.com/contacts
Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green
Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality

For more National Semiconductor product information and proven design tools, visit the following Web sites at:

Products

www.national.com/lvds

www.national.com/ldo

www.national.com/led

www.national.com/sdi

www.national.com/power

www.national.com/switchers

www.national.com/powerwise

www.national.com/tempsensors

www.national.com/wireless

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION
("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY
OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO
SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS,
IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS
DOCUMENT

Reference Designs

Feedback

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2008 National Semiconductor Corporation

For the most current product information visit us at www.national.com



National Semiconductor Americas Technical Support Center Email: support@nsc.com Tel: 1-800-272-9959 National Semiconductor Europe Technical Support Center Email: europe.support@nsc.com German Tel: +49 (0) 180 5010 771 English Tel: +44 (0) 870 850 4288 National Semiconductor Asia Pacific Technical Support Center Email: ap.support@nsc.com National Semiconductor Japan Technical Support Center Email: jpn.feedback@nsc.com